1. General description

NPN high-voltage low V_{CEsat} transistor in a SOT223 (SC-73) medium power Surface-Mounted Device (SMD) plastic package.

PNP complement: PBHV9560Z-Q

2. Features and benefits

- Low collector-emitter saturation voltage V_{CEsat}
- High collector current capability
- High collector current gain h_{FE} at high I_C
- · Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

- · Electronic ballast for fluorescent lighting
- · LED driver for LED chain module
- LCD backlighting
- · High Intensity Discharge (HID) front lighting
- Automotive motor management
- · Hook switch for wired telecom
- Switch Mode Power Supply (SMPS)

4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-------------------|--------------------------------|--|-----|-----|-----|------|
| V _{CESM} | collector-emitter peak voltage | V _{BE} = 0 V | - | - | 600 | ٧ |
| V _{CEO} | collector-emitter voltage | open base | - | - | 600 | V |
| I _C | collector current | | - | - | 0.5 | Α |
| h _{FE} | DC current gain | V _{CE} = 10 V; I _C = 50 mA; T _{amb} = 25 °C | 70 | 135 | - | |



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600 V, 0.5 A NPN high-voltage low VCEsat transistor

5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-------------|----------------------------------|--|
| 1 | В | base | 4 | C; C |
| 2 | С | collector | | В |
| 3 | E | emitter | | B————————————————————————————————————— |
| 4 | С | collector | <u>∃</u> 1 <u>∃</u> 2 <u>∃</u> 3 | Ė |
| | | | SC-73 (SOT223) | sym016 |

6. Ordering information

Table 3. Ordering information

| Type number | Package | | | | | |
|-------------|---------|---|---------|--|--|--|
| | Name | Description | Version | | | |
| PBHV8560Z-Q | | plastic, surface-mounted package with increased heatsink; 4 leads; 2.3 mm pitch; 6.5 mm x 3.5 mm x 1.65 mm body | SOT223 | | | |

7. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| PBHV8560Z-Q | HV856Z |

8. Limiting values

Table 5. Limiting values

PBHV8560Z-Q

In accordance with the Absolute Maximum Rating System (IEC 60134).

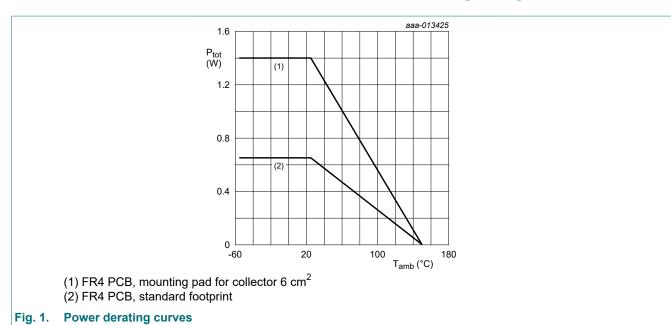
| Symbol | Parameter | Conditions | | Min | Max | Unit |
|-------------------|--------------------------------|--------------------------|-----|-----|------|------|
| V_{CBO} | collector-base voltage | open emitter | | - | 600 | V |
| V_{CEO} | collector-emitter voltage | open base | | - | 600 | V |
| V _{CESM} | collector-emitter peak voltage | V _{BE} = 0 V | | - | 600 | V |
| V_{EBO} | emitter-base voltage | open collector | | - | 6 | V |
| I _C | collector current | | | - | 0.5 | А |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | [1] | - | 0.65 | W |
| | | | [2] | - | 1.4 | W |
| T _j | junction temperature | | | - | 150 | °C |
| T _{amb} | ambient temperature | | | -55 | 150 | °C |
| T _{stg} | storage temperature | | | -65 | 150 | °C |

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

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Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

600 V, 0.5 A NPN high-voltage low VCEsat transistor



9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|-----------------------|--|-------------|-----|-----|-----|-----|------|
| R _{th(j-a)} | thermal resistance from | in free air | [1] | - | - | 190 | K/W |
| | junction to ambient | | [2] | - | - | 89 | K/W |
| R _{th(j-sp)} | thermal resistance from junction to solder point | | | - | - | 20 | K/W |

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

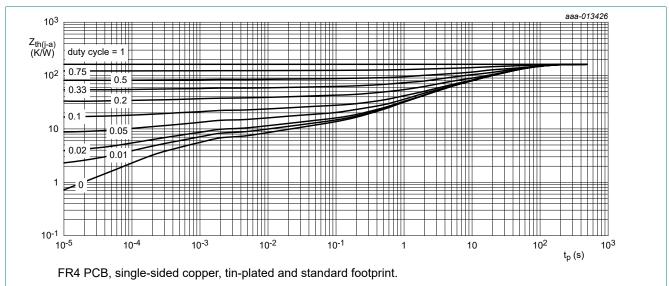
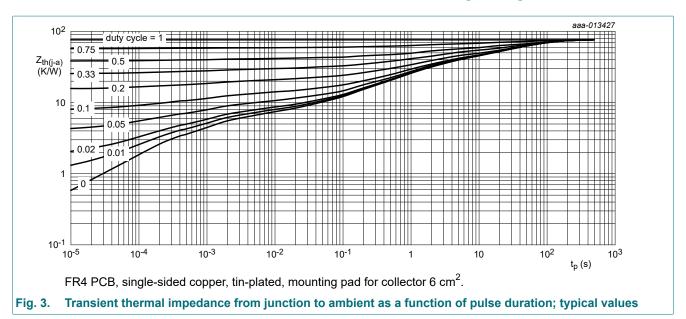


Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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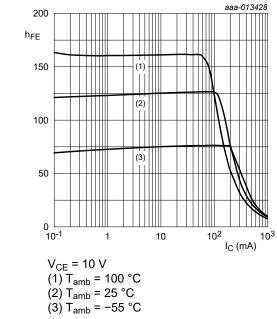
10. Characteristics

Table 7. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--------------------|--------------------------------------|---|-----|-----|-----|------|
| I _{CBO} | collector-base cut-off | V _{CB} = 400 V; I _E = 0 A; T _{amb} = 25 °C | - | - | 100 | nA |
| | current | V _{CB} = 400 V; I _E = 0 A; T _j = 150 °C | - | - | 10 | μΑ |
| I _{EBO} | emitter-base cut-off current | V _{EB} = 4 V; I _C = 0 A; T _{amb} = 25 °C | - | - | 100 | nA |
| I _{CES} | collector-emitter cut-off current | V _{CE} = 400 V; V _{BE} = 0 V; T _{amb} = 25 °C | - | - | 100 | nA |
| h _{FE} | DC current gain | V _{CE} = 10 V; I _C = 50 mA; T _{amb} = 25 °C | 70 | 135 | - | |
| | | V_{CE} = 10 V; I_{C} = 100 mA; $t_{p} \le 300$ μs; $\delta \le 0.02$; T_{amb} = 25 °C; pulsed | 70 | 135 | - | |
| V _{CEsat} | collector-emitter saturation voltage | I _C = 50 mA; I _B = 5 mA; T _{amb} = 25 °C | - | 50 | 100 | mV |
| | | I_C = 100 mA; I_B = 20 mA; $t_p \le 300$ μs; $δ \le 0.02$; T_{amb} = 25 °C; pulsed | - | 50 | 100 | mV |
| V _{BEsat} | base-emitter saturation voltage | I_C = 50 mA; I_B = 5 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C | - | - | 950 | mV |
| C _c | collector capacitance | $V_{CB} = 20 \text{ V}; I_E = 0 \text{ A}; i_e = 0 \text{ A}; f = 1 \text{ MHz}; T_{amb} = 25 ^{\circ}\text{C}$ | - | 7.5 | - | pF |
| C _e | emitter capacitance | $V_{EB} = 0.5 \text{ V}; I_{C} = 0 \text{ A}; i_{c} = 0 \text{ A};$ f = 1 MHz; $T_{amb} = 25 \text{ °C}$ | - | 710 | - | pF |

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(2)
$$I_{amb} = 25 \,^{\circ}C$$

Fig. 4. DC current gain as a function of collector current; typical values

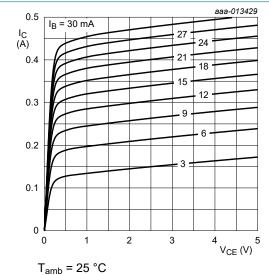
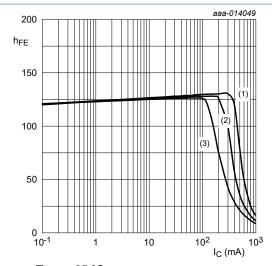


Fig. 6. Collector current as a function of collectoremitter voltage; typical values



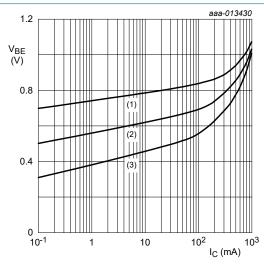
$$T_{amb} = 25 \,^{\circ}C$$

$$(1) V_{CE} = 50 V_{CE}$$

$$T_{amb}$$
 = 25 °C
(1) V_{CE} = 50 V
(2) V_{CE} = 25 V
(3) V_{CE} = 10 V

$$(3) V_{CE} = 10 V$$

Fig. 5. DC current gain as a function of collector current; typical values



$$V_{CE}$$
 = 10 V

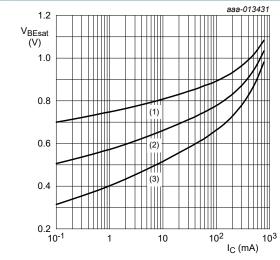
$$(1) T_{amb} = -55 °C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

$$(3) T_{amb} = 100 °C$$

Fig. 7. Base-emitter voltage as a function of collector current; typical values

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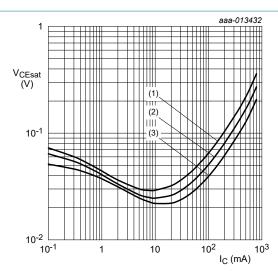
 $I_C/I_B = 5$

(1)
$$T_{amb} = -55 \,^{\circ}C$$

(2) $T_{amb} = 25 \,^{\circ}C$

(3) T_{amb}= 100 °C

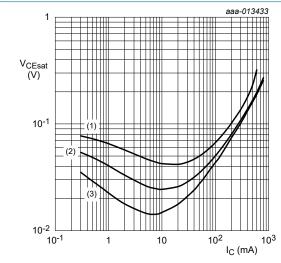
Fig. 8. Base-emitter saturation voltage as a function of Fig. 9. collector current; typical values



$$(1) T_{amb} = 100 °C$$

I_C/I_B = 5 (1) T_{amb} = 100 °C (2) T_{amb} = 25 °C (3) T_{amb} = -55 °C

Collector-emitter saturation voltage as a function of collector current; typical values

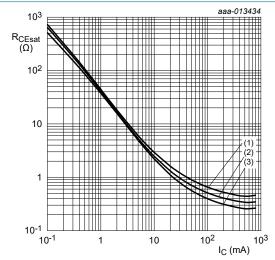


T_{amb} = 25 °C

(1) $I_C/I_B = 10$ (2) $I_C/I_B = 5$

 $(3) I_{\rm C}/I_{\rm B} = 2.5$

Fig. 10. Collector-emitter saturation voltage as a function of collector current; typical values



 $I_C/I_B = 5$

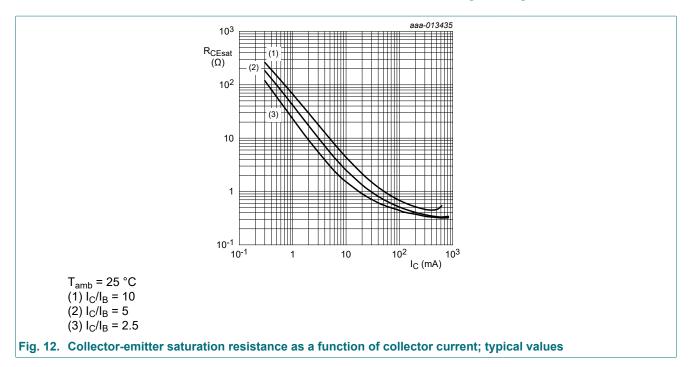
(1) T_{amb} = 100 °C

(2) $T_{amb} = 25 \, ^{\circ}C$

(3) $T_{amb} = -55 \, ^{\circ}C$

Fig. 11. Collector-emitter saturation resistance as a function of collector current; typical values

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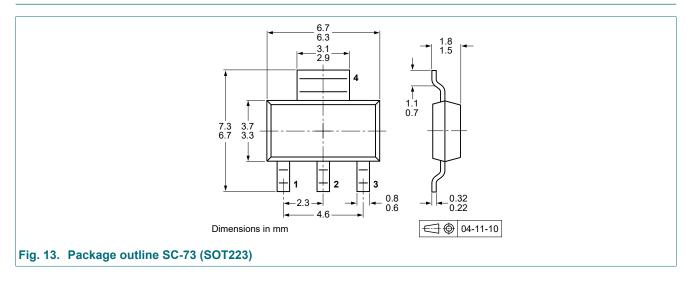


11. Test information

Quality information

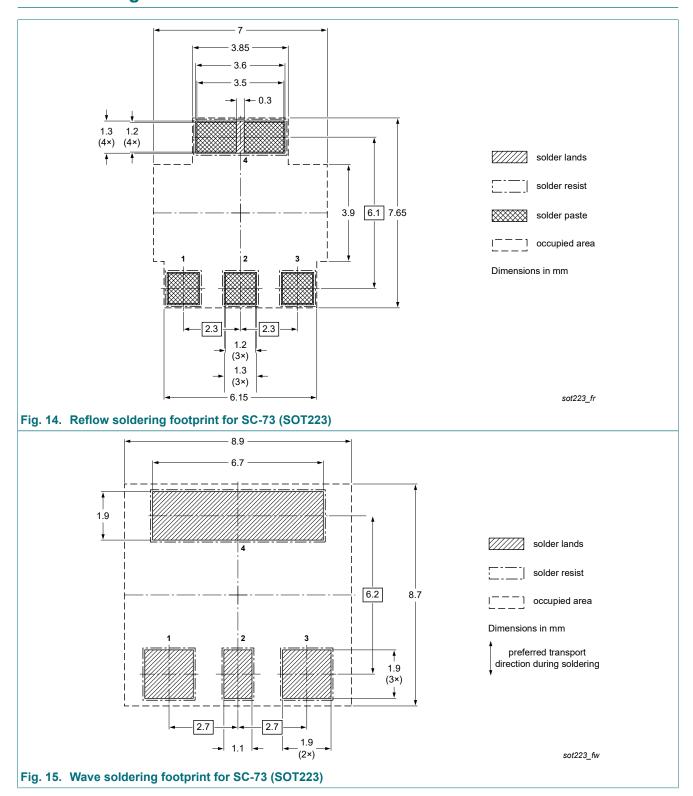
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



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13. Soldering



600 V, 0.5 A NPN high-voltage low VCEsat transistor

14. Revision history

Table 8. Revision history

| Data sheet ID | Release date | Data sheet status | Change notice | Supersedes |
|-----------------|--------------|--------------------|---------------|------------|
| PBHV8560Z-Q v.1 | 20230717 | Product data sheet | - | - |

15. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

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